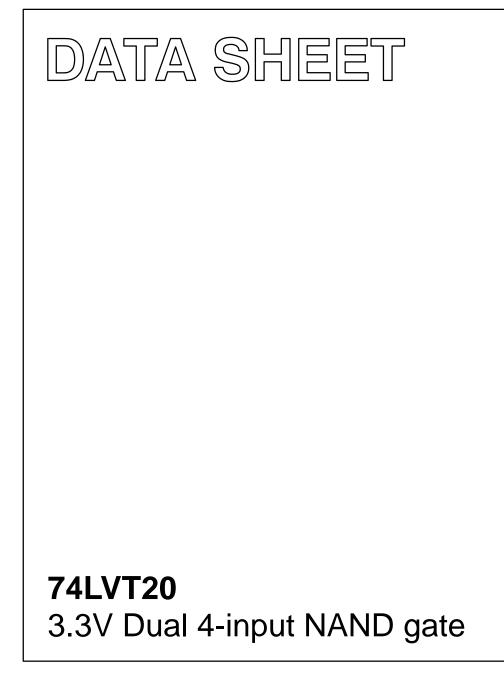
INTEGRATED CIRCUITS



Product specification IC24 Data Handbook 1996 Aug 28



Philips Semiconductors

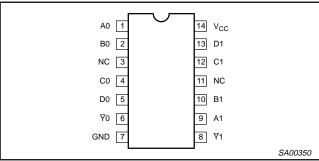


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QUICK REFERENCE DATA

SYMBOL	PARAMETER T _{amb} = 25°C; GND = 0V		TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay An, Bn, Cn, Dn to Yn	C _L = 50pF; V _{CC} = 3.3V	3.4 3.2	ns
C _{IN}	Input capacitance	V _I = 0V or 3.0V	3	pF
I _{CCL}	Total supply current	Outputs Low; V _{CC} = 3.6V	0.5	mA

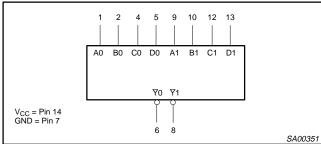
PIN CONFIGURATION



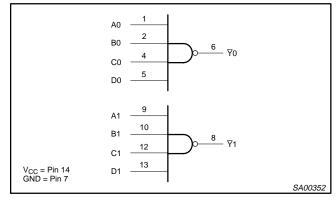
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 2, 4, 5, 9, 10, 12, 13	An, Bn, Cn, Dn	Data inputs
6, 8	Ϋ́n	Data outputs
7	GND	Ground (0V)
14	V _{CC}	Positive supply voltage

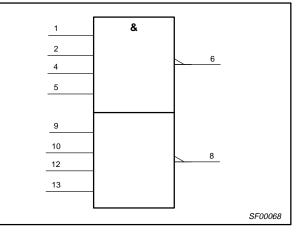
LOGIC SYMBOL



LOGIC DIAGRAM



LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

	OUTPUT			
Dna	Dnb	Dnc	Dnd	Qn
L	Х	Х	Х	Н
Х	L	Х	Х	Н
Х	Х	L	Х	Н
Х	Х	X	L	Н
Н	Н	Н	Н	L

NOTES:

H = High voltage level

L = Low voltage level

X = Don't care

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	–40°C to +85°C	74LVT20 D	74LVT20 D	SOT108-1
14-Pin Plastic SSOP	-40°C to +85°C	74LVT20 DB	74LVT20 DB	SOT337-1
14-Pin Plastic TSSOP	-40°C to +85°C	74LVT20 PW	74LVT20PW DH	SOT402-1

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ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
		Output in High state	-32	
IOUT	DC output current	Output in Low state	64	mA
T _{stg}	Storage temperature range		–65 to 150	°C

NOTES:

Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the 1. device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction 2.

The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER		LIMITS	
STMBOL		MIN	MAX	UNIT
V _{CC}	DC supply voltage	2.7	3.6	V
VI	Input voltage		5.5	V
V _{IH}	High-level input voltage			V
V _{IL}	Low-level Input voltage		0.8	V
I _{OH}	High-level output current		-20	mA
	Low-level output current		32	mA
IOL	Low-level output current; current duty cycle \leq 50%, f \geq 1kHz		48	ША
T _{amb}	Operating free-air temperature range		+85	°C

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions Voltages are referenced to GND (ground = 0V)

			LIMITS Temp = -40°C to +85°C			UNIT	
SYMBOL	PARAMETER	TEST CONDITIONS					
			MIN	TYP ¹	MAX	1	
V _{IK}	Input clamp voltage	V _{CC} = 2.7V; I _{IK} = -18mA			-1.2	V	
		$V_{CC} = 2.7$ to 3.6V; $I_{OH} = -100\mu A$	V _{CC} -0.2				
V _{OH}	High-level output voltage	V _{CC} = 2.7V; I _{OH} = -6mA	2.4			V	
		$V_{CC} = 3.0V; I_{OH} = -20mA$	2.0				
V _{OL} Low-level of	Low-level output voltage	V _{CC} = 2.7V; I _{OL} = 100µA			0.2		
		V _{CC} = 2.7V; I _{OL} = 24mA			0.5	V	
		V _{CC} = 3.0V; I _{OL} = 32mA			0.5		
1	$V_{\rm CC} = 0$ of	V _{CC} = 0 or 3.6V; V _I = 5.5V			10		
łı	Input leakage current	$V_{CC} = 3.6$ V; $V_{I} = V_{CC}$ or GND			±1	μA	
I _{OFF}	Output off current	$V_{CC} = 0V$; V_{I} or $V_{O} = 0$ to 4.5V			±100	μA	
I _{ССН}		V_{CC} = 3.6V; Outputs High, V_{I} = GND or V_{CC}, I_{O} = 0			0.02	mA	
I _{CCL}	Quiescent supply current	V_{CC} = 3.6V; Outputs Low, V_{I} = GND or $V_{CC,}$ I_{O} = 0		0.5	1.2		
ΔI_{CC}	Additional supply current per input pin ²	V_{CC} = 3V to 3.6V; One input at V_{CC} –0.6V, Other inputs at V_{CC} or GND			0.2	μA	
Cl	Input capacitance	$V_1 = 3V \text{ or } 0$		3		pF	

NOTES:

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C. 2. This is the increase in supply current for each input at the specificed voltage level other than V_{CC} or GND.

AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$, $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to $+85^{\circ}C$.

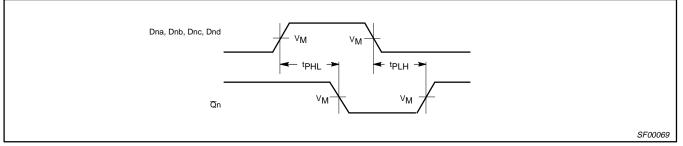
			LIMITS				
SYMBOL PARAMETER		WAVEFORM V _{CC}		$_{ m C}$ = 3.3V \pm 0.3V		V _{CC} = 2.7V	UNIT
			MIN	TYP ¹	MAX	MAX	
t _{PLH} t _{PHL}	Propagation delay An, Bn, Cn, Dn to Yn	1	1.0 1.0	3.4 3.2	5.4 4.4	6.4 4.3	ns

NOTE:

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25° C.

AC WAVEFORMS

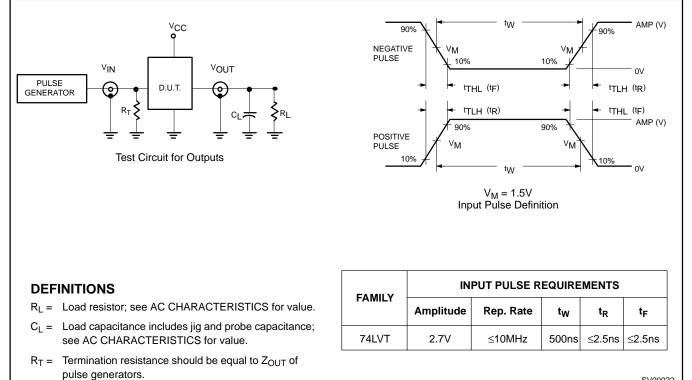
 V_{M} = 1.5V, V_{IN} = GND to 2.7V



Waveform 1. Propagation Delay for Inverting Outputs

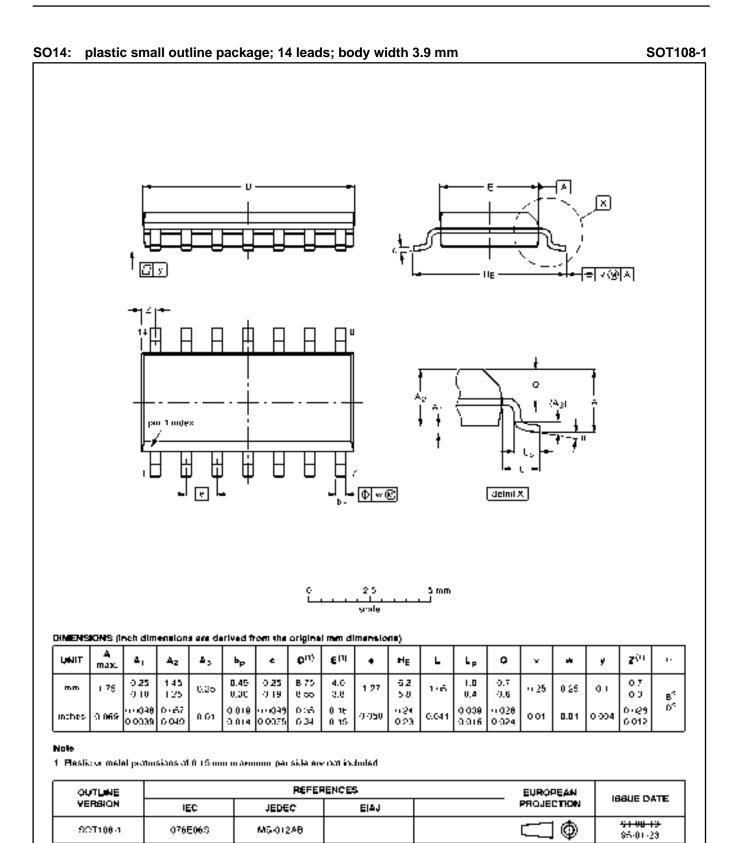
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TEST CIRCUIT AND WAVEFORMS

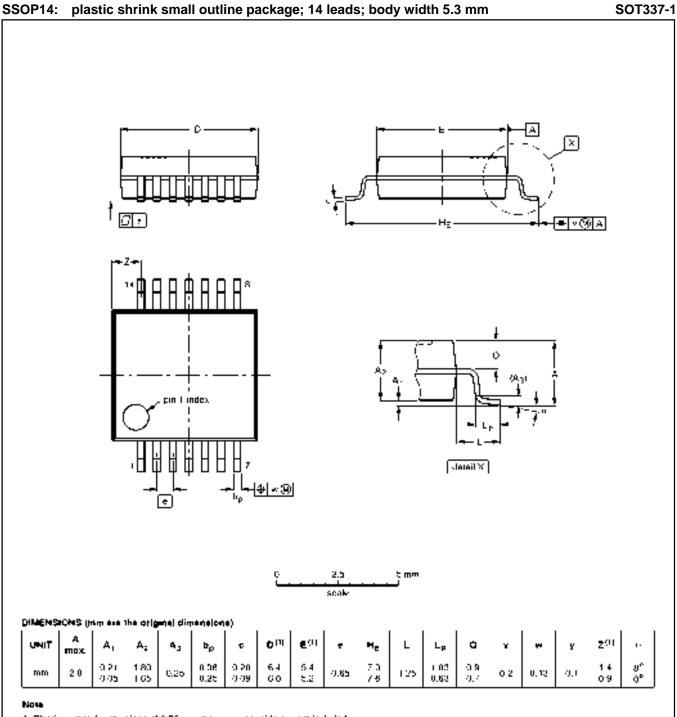


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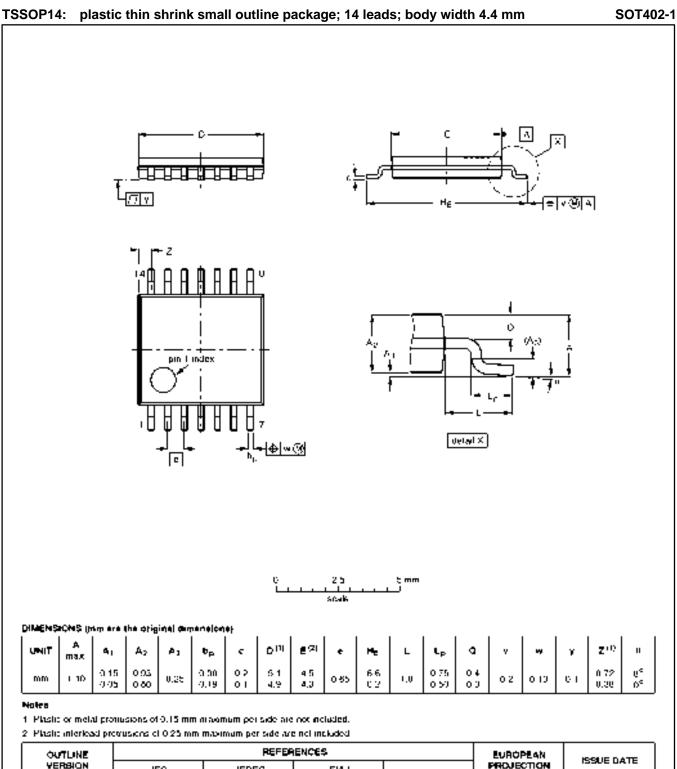
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1. Plastic or metal protocions of 0.25 non-maximum per side any not included

OUTLINE		REFERENCES			
VERBION	IEC	JEDEC	EITÌ	PROJECTION	IBOUE DATE
SOT007-1		MO-150AB		€∃\$	-95-82-94 96-01-19

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NOTES

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DEFINITIONS				
Data Sheet Identification	Product Status	Definition		
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.		
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.		
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